NSN 5961-01-055-8657

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-055-8657 **Inclosure Material:** Glass and metal **Overall Length:** Between 1.570 inches and 1.750 inches **Mounting Facility Quantity: Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** Between 1.052 inches and 1.063 inches Thread Size: 0.190 inches **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 1300.0 reverse voltage, peak **Current Rating Per Characteristic:** 2500.00 amperes forward current, average preset **Test Data Document:** 55717-+19500-032 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 tab, solder lug and 1 threaded stud Shelf Life: N/a **Unit Of Measure: Demilitarization:** No